TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MZ157FK

Low Voltage Quad 2-Channel Multiplexer with 5 V Tolerant Inputs and Outputs

The TC7MZ157FK is a high performance CMOS multiplexer. Designed for use in 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) V<sub>CC</sub> applications, but it could be used to interface to 5 V supply environment for inputs.

It consists of four 2-input digital multiplexers with common select and strobe inputs.

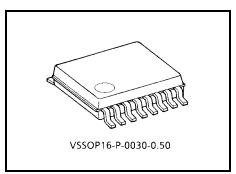
When the strobe input  $(\overline{ST})$  is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.

#### Features

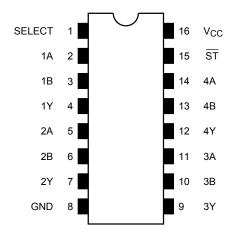
- Low voltage operation:  $V_{CC} = 2.0 \sim 3.6 \text{ V}$
- High speed operation:  $t_{pd} = 5.8 \text{ ns} (max) (V_{CC} = 3.0 \sim 3.6 \text{ V})$
- Output current: |IOH|/IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: -500 mA
- Package: VSSOP16 (US16)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 157 type.



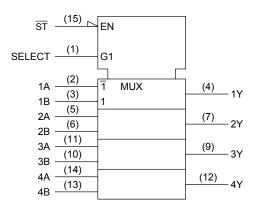
Weight: 0.02 g (typ.)

# <u>TOSHIBA</u>

# Pin Assignment (top view)



# **IEC Logic Symbol**



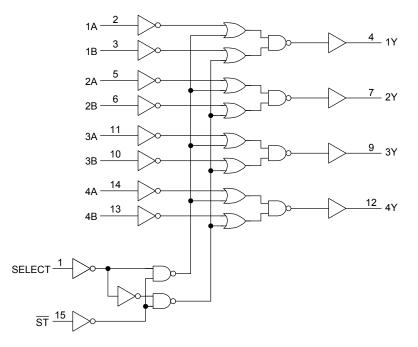
### **Truth Table**

	Outputs			
ST	Select A B			Y
н	Х	х	х	L
L	L	L	Х	L
L	L	Н	Х	н
L	Н	Х	L	L
L	Н	Х	Н	н

X: Don't care

# <u>TOSHIBA</u>

#### System Diagram



#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V <sub>CC</sub>	-0.5~7.0	V	
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V	
DC output voltage	Vour	-0.5~7.0 (Note 2)	V	
DC oulput voltage	Vout	-0.5~V <sub>CC</sub> + 0.5 (Note 3)	v	
Input diode current	IIК	-50	mA	
Output diode current	I <sub>OK</sub>	±50 (Note 4)	mA	
DC output current	IOUT	±50	mA	
Power dissipation	PD	180	mW	
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2:  $V_{CC} = 0 V$
- Note 3: High or low state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND, V_{OUT} > V_{CC}$ 

#### **Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0~3.6	V	
Supply vollage	VCC	1.5~3.6 (Note 2)	v	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	Vout	0~5.5 (Note 3)	V	
Output voltage		0~V <sub>CC</sub> (Note 4)	v	
Output current	Іон/Іог	±24 (Note 5)	mA	
Output current	IOH/IOL	±12 (Note 6)	IIIA	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3:  $V_{CC} = 0 V$ 

Note 4: High or low state

Note 5:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 6:  $V_{CC} = 2.7 \sim 3.0 \text{ V}$ 

Note 7:  $V_{IN} = 0.8 \text{--} 2.0 \text{ V}, \text{ V}_{CC} = 3.0 \text{ V}$ 

#### **Electrical Characteristics**

#### DC Characteristics ( $Ta = -40 \sim 85^{\circ}C$ )

Characteristics		Symbol	Test Condition			Min	Max	Unit
Cildidute	ensues	Symbol			V <sub>CC</sub> (V)	IVIIII	WITT WAX	
Input voltage	High level	VIH		_	2.7~3.6	2.0	_	v
input voitage	Low level	VIL		—	2.7~3.6	_	0.8	v
			I <sub>OH</sub> = -100 μA	2.7~3.6	V <sub>CC</sub> - 0.2	_		
	High level	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	V
				$I_{OH} = -18 \text{ mA}$	3.0	2.4		
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
		/ level V <sub>OL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	2.7~3.6	—	0.2	
				$I_{OL} = 12 \text{ mA}$	2.7	—	0.4	
	LOWIEVEI			$I_{OL} = 16 \text{ mA}$	3.0	—	0.4	
			$I_{OL} = 24 \text{ mA}$	3.0	—	0.55		
Input leakage current		lin	$V_{IN} = 0 \sim 5.5 V$		2.7~3.6	—	±5.0	μA
Power off leakage current $I_{OFF}$ $V_{IN}/V_{OUT} = 5.5 V$		0	—	10.0	μA			
Quiescent supply current		Icc	$V_{IN} = V_{CC} \text{ or } GND$		2.7~3.6		10.0	
Quiescent supply cullent	-CC	V <sub>IN</sub> = 3.6~5.5 V		2.7~3.6	—	±10.0	μA	
Increase in I <sub>CC</sub> per input		Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	500	

#### AC Characteristics (Ta = -40~85°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	_	6.3	ns
(A, B-Y)	t <sub>pHL</sub>		$\textbf{3.3}\pm\textbf{0.3}$	1.5	5.8	
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	_	8.0	20
(SELECT-Y)	t <sub>pHL</sub>		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	ns
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	_	8.0	20
( <del>ST</del> -Y)	t <sub>pHL</sub>		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	ns
Output to output skew	t <sub>osLH</sub>	(Note)	2.7	_	_	20
	t <sub>osHL</sub>	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	ns

Note: This parameter is guaranteed by design.

 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$ 

#### Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic VOL	V <sub>OLP</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic VOL	V <sub>OLV</sub>	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	C <sub>OUT</sub>	_	0	8	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note)	3.3	25	pF

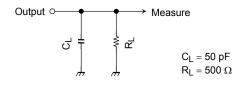
Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

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### **AC Test Circuit**





#### **AC Waveform**

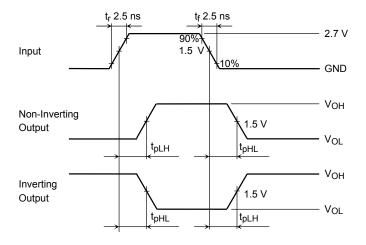
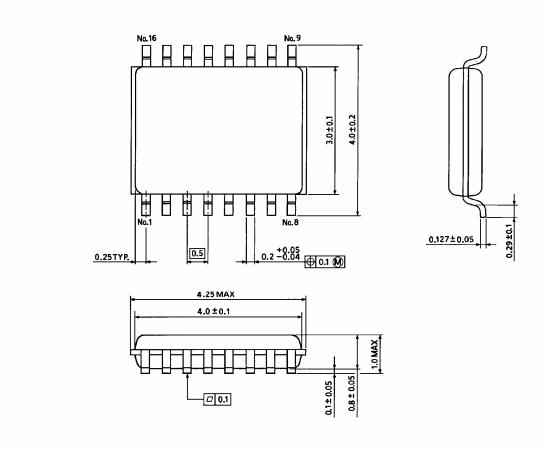


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

### Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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